NSN 5961-01-249-1031

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-1031 **Inclosure Material:** Metal **Overall Length:** 0.080 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-46 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.2 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes forward current, average peak and 10.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No